HiPSTER® 1

A flexible HiPIMS pulser for the latest generation of coatings



HiPSTER 1 HiPIMS Pulser

Our HiPSTER HiPIMS units are designed by experts in the field with an excellent track record of plasma process development and thin film deposition in order to generate robust and repeatable HiPIMS processes.

With the new ultra-fast switching technology and extended HiPIMS pulse control the HiPSTER is a perfect tool when developing and running state-of-the-art HiPIMS processes. Also, upgrading your existing magnetron system to HiPIMS has never been easier. The HiPSTER can be directly connected either to an existing DC supply or to one of our tailor-made HiPSTER DC units.

FEATURES

- Stable and robust discharge process (constant voltage and no unwanted oscillations)
- Can be triggered externally (multiple power supplies)
- New switching technology allowing HiPIMS pulsing frequencies up to 10 kHz
- Tested using a wide range of magnetrons and processes (incl. reactive HiPIMS)
- Real-time information on the discharge pulse voltage
 and current
- Add Ionautics' superposition technology for HiPIMS + DC

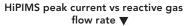
APPLICATIONS

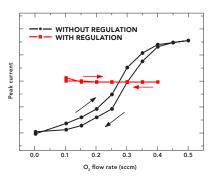
- Hard coatings: Smoother and denser elemental as well as reactively deposited compound coatings, which result in increased hardness, reduced corrosion, and less friction
- Optical coatings: Increased optical properties
 through smoother interfaces and denser structures
- Diffusion barriers: Better performance through increased coating density
- Electrical coatings: Improved conductivity enabling reduced coating thickness and reduced heat load.
 Also increased isolation in the case of insulators can be obtained
- 3-D coatings: Uniform film coverage on complex shaped substrates





HiPIMS pulse current vs reactive gas ▼ flow rate ▼ WITHOUT REGULATION WITH REGULATION Discharge current Discharge current — 0.1 sccm — 0.2 sccm 0.1 sccm — 0.2 sccm - 0.3 sccm 0.3 sccm 0.4 sccm 0.4 sccm 0.5 sccm 0.5 sccm 0.6 sccm 0.6 sccm -10 30 10 10 20 Time (µS) Time (µS)





1 phase + N, 100-240 VAC, 50/60 Hz

1000 V max, positive grounded

Ground-Referenced 5V CMOS input

135 mm (H) x 483 mm (W) x 390 mm (D)

0.3 A

19" rack (3U)

+5°C to + 40°C -25°C to +55°C

80 kPa to 106 kPa

conductive particles.

Air Cooling

CE marked

max 85% non-condensing

2 (or better). Cooling air must normally

be free of corrosive vapors and

8,5 kg

Output Specifications

Output Average Power:	≤ 1000 W
Output Peak Voltage:	≤ 1000 V
Output Peak Current:	≤ 100 A
Regulation Modes:	Voltage, Current,
	Power, Pulse current
Pulse Frequency:	50 to 10 000 Hz*
Pulse Duration:	3.5 µs to 1000 µs
Arc control - reaction time:	< 2 µs

* External triggering has an extended range; contact lonautics for more details.





DANIEL LUNDIN Professor

Expert in the field of HiPIMS processes and magnetron sputtering with focus on deposition processes and process characterization.



ULF HELMERSSON Professor

Input Specifications

Input Current at 230 V:

Environmental Specifications

Operating Temperature:

Storage Temperature: Relative Humidity:

Air Pressure:

Pollution degree:

Cooling:

Norms:

DC Charging Input:

Trigger In:

Size:

Weight:

Dimensions

Input Voltage AC:

Expert in the field of physical vapor deposition, such as magnetron sputtering and HiPIMS processes with focus on material science.



CONTACT>>>>

RAFAEL SANCHEZ Global Sales Manager

In charge of sales and marketing worldwide. 10 years of experience in thin film deposition using magnetron sputtering.

Tel: +46-704 39 76 76 E-mail: rafael.sanchez @ionautics.com

SWEDEN: LINKÖPING: STORA TORGET 3, 582 19 LINKÖPING, SWEDEN PITEÅ (POSTAL AND SHIPPING ADDRESS) KABELGATAN 9B, SE-943 31 ÖJEBYN, SWEDEN STOCKHOLM: STRANDVÄGEN 1, 114 51 STOCKHOLM, SWEDEN USA: POSTAL ADDRESS: 19924 163RD AVE NE WOODINVILLE WA 98072 USA

